



BYV29FX-600

Enhanced ultrafast power diode

Rev. 5 — 16 April 2012

Product data sheet

1. Product profile

1.1 General description

Enhanced ultrafast power diode in a SOD113 (2-lead TO-220F) plastic package.

1.2 Features and benefits

- High thermal cycling performance
- Isolated package
- Low on-state losses
- Low thermal resistance
- Soft recovery characteristic

1.3 Applications

- Dual Mode (DCM and CCM) PFC
- Power Factor Correction (PFC) for Interleaved Topology

1.4 Quick reference data

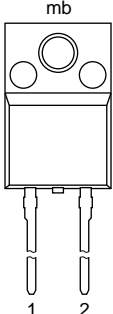

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
$I_{F(AV)}$	average forward current	square-wave pulse; $\delta = 0.5$; $T_h \leq 72$ °C; see Figure 1 ; see Figure 2	-	-	9	A
Static characteristics						
V_F	forward voltage	$I_F = 8$ A; $T_j = 25$ °C; see Figure 5	-	1.45	1.9	V
		$I_F = 8$ A; $T_j = 150$ °C; see Figure 5	-	1.25	1.7	V



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	n.c.	mounting base; isolated		

SOD113 (TO-220F)

3. Ordering information

Table 3. Ordering information

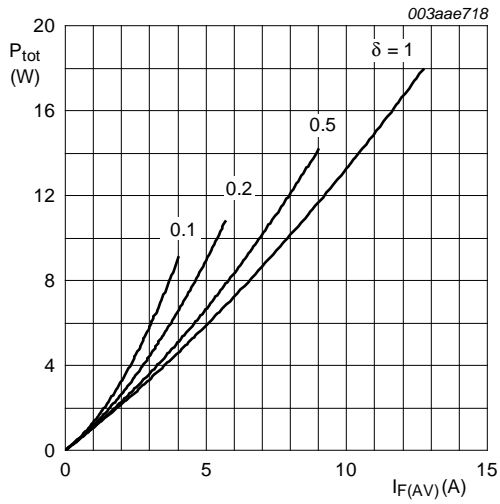
Type number	Package		
	Name	Description	Version
BYV29FX-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

4. Limiting values

Table 4. Limiting values

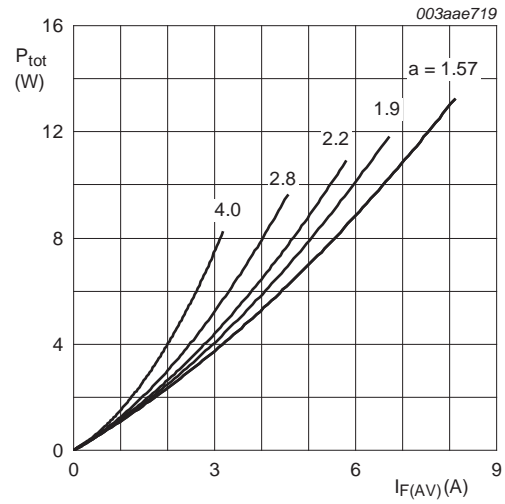
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	DC	-	600	V
$I_{F(AV)}$	average forward current	square-wave pulse; $\delta = 0.5$; $T_h \leq 72$ °C; see Figure 1 ; see Figure 2	-	9	A
I_{FRM}	repetitive peak forward current	square-wave pulse; $\delta = 0.5$; $t_p = 25$ μ s; $T_h \leq 72$ °C	-	18	A
I_{FSM}	non-repetitive peak forward current	sine-wave pulse; $t_p = 10$ ms; $T_{j(init)} = 25$ °C; see Figure 3	-	91	A
		sine-wave pulse; $t_p = 8.3$ ms; $T_{j(init)} = 25$ °C; see Figure 3	-	100	A
T_{stg}	storage temperature		-40	150	°C
T_j	junction temperature		-	150	°C



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

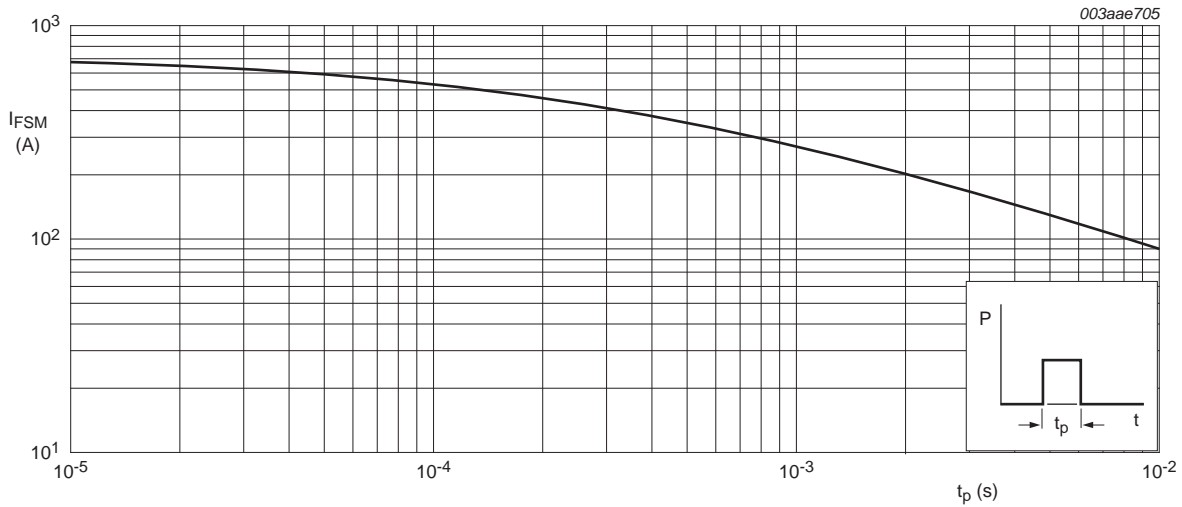


Fig 3. Non-repetitive peak forward current as a function of pulse width; square waveform; maximum values

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	with heatsink compound ; see Figure 4	-	-	5.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air		-	55	-	K/W

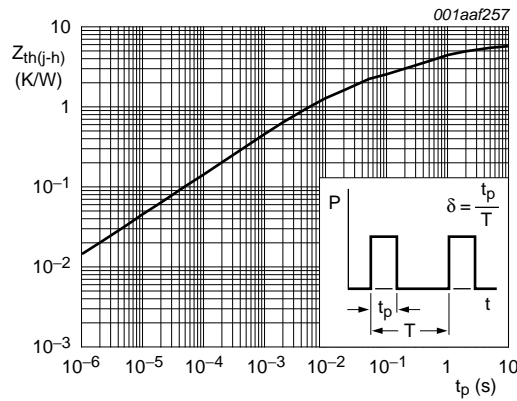


Fig 4. Transient thermal impedance from junction to heatsink as a function of pulse width

6. Isolation characteristics

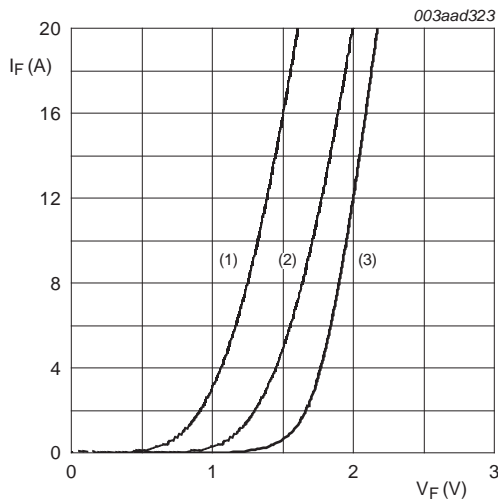
Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	$50 \text{ Hz} \leq f \leq 60 \text{ Hz}$; $RH \leq 65 \%$; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C_{isol}	isolation capacitance	$f = 1 \text{ MHz}$; from cathode to external heatsink	-	10	-	pF

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward voltage	$I_F = 8\text{ A}; T_j = 25\text{ °C};$ see Figure 5	-	1.45	1.9	V
		$I_F = 8\text{ A}; T_j = 150\text{ °C};$ see Figure 5	-	1.25	1.7	V
I_R	reverse current	$V_R = 600\text{ V}; T_j = 25\text{ °C}$	-	-	50	μA
		$V_R = 600\text{ V}; T_j = 100\text{ °C}$	-	-	1.5	mA
Dynamic characteristics						
Q_r	recovered charge	$I_F = 1\text{ A}; V_R = 30\text{ V}; dI_F/dt = 100\text{ A/s};$ $T_j = 25\text{ °C};$ see Figure 6	-	13	-	nC
t_{rr}	reverse recovery time	$T_j = 25\text{ °C};$ see Figure 6	-	17.5	35	ns
I_{RM}	peak reverse recovery current		-	1.5	-	A
V_{FRM}	forward recovery voltage	$I_F = 1\text{ A}; dI_F/dt = 100\text{ A/s}; T_j = 25\text{ °C};$ see Figure 7	-	3.2	-	V



- (1) $T_j = 150\text{ °C};$ typical values
- (2) $T_j = 150\text{ °C};$ maximum values
- (3) $T_j = 25\text{ °C};$ maximum values

Fig 5. Forward current as a function of forward voltage

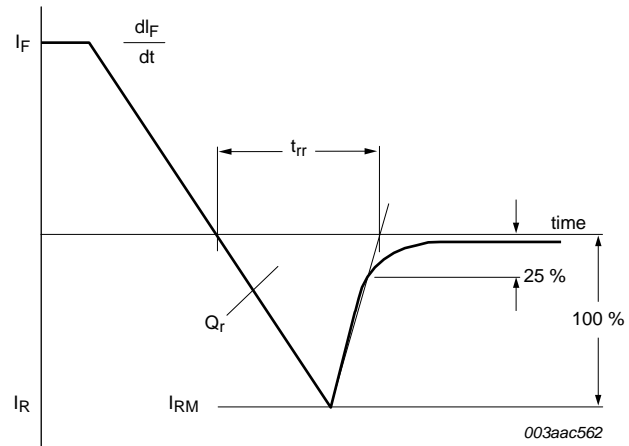


Fig 6. Reverse recovery definitions; ramp recovery

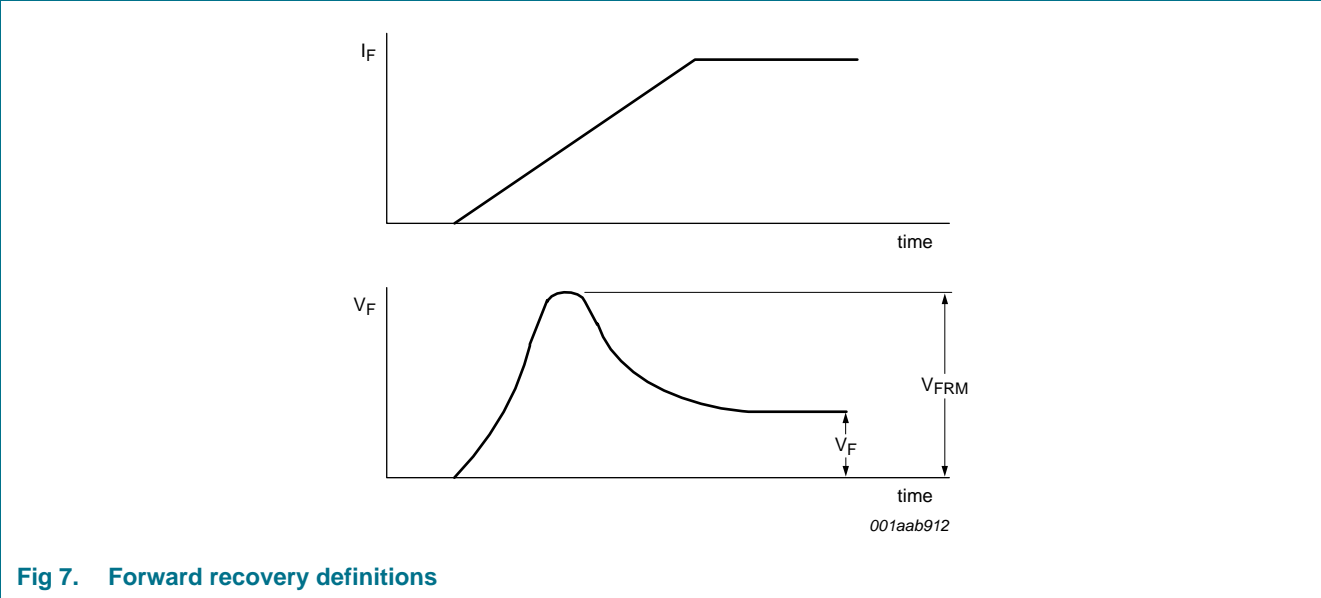


Fig 7. Forward recovery definitions

8. Package outline

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 2-lead TO-220 'full pack'

SOD113

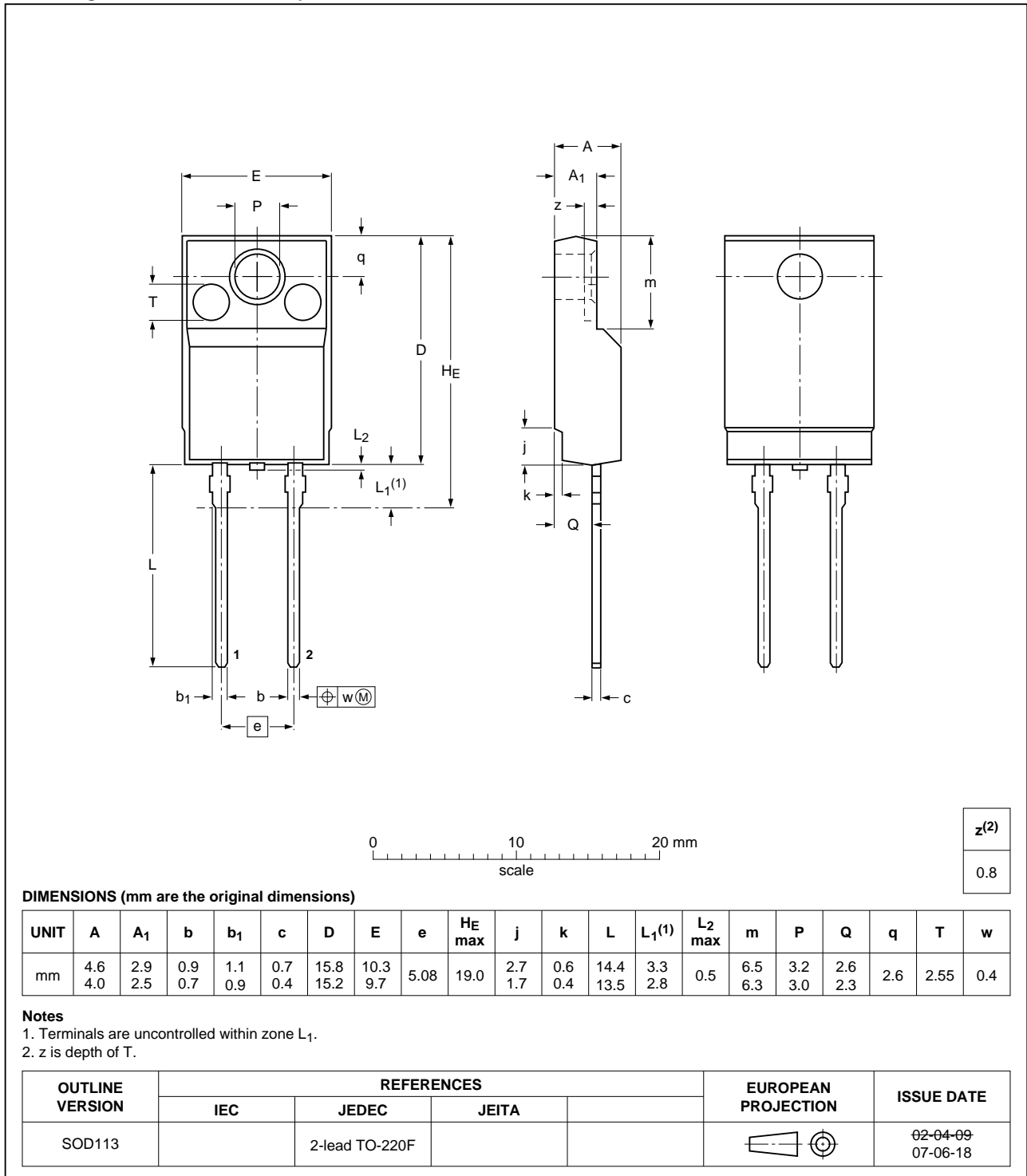


Fig 8. Package outline SOD113 (TO-220F)

9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV29FX-600 v.5	20120416	Product data sheet	-	BYV29FX-600 v.4
Modifications:	• Various changes to content.			
BYV29FX-600 v.4	20110307	Product data sheet	-	BYV29FX-600 v.3

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Document status ^[1] ^[2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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